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Examiner Initials*		U.S. Patent Document		Name of Patentee or Applicant	Date of Publication	Pages, Columns, Lines, Where	
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Substitute for form 14490/TO			2007	Application Number	09/991,893		
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			Filing Date	11/05/01		
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			Group Art Unit	2872 2874		
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SHEET 3	OF	6	Docket Number	LIGHT2180		

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First Named Inventor Lin

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				Group Art Unit	2872 28 14
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SHEET	8	OF	6	Docket Number	LIGHT2180

			OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.1		Include name of the author (in CAPITAL LETTERS), little of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published				
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